Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-455-5981

Inclosure Material:	erial:	Mat	losure	Inc
---------------------	--------	-----	--------	-----

Metal

Overall Length:

0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

45.0 collector to emitter voltage/static/base open all transistor and 45.0 collector to base voltage/static/emitter open all transistor and 5.0

emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector preset all transistor

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0